

## Document Title

1Mx8 bit Low Power and Low Voltage CMOS Static RAM

## Revision History

<u>Revision No.</u>	<u>History</u>	<u>Draft Date</u>	<u>Remark</u>
0.0	Initial draft	October 31, 2002	Preliminary
0.1	Revised - Deleted 44-TSOP2-400R package type.	December 11, 2002	Preliminary

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## 1Mx8 bit Low Power and Low Voltage full CMOS Static RAM

### FEATURES

- Process Technology: Full CMOS
- Organization: 1M x8
- Power Supply Voltage: 2.7~3.6V
- Low Data Retention Voltage: 1.5V(Min)
- Three state outputs
- Package Type: 44-TSOP2-400F

### GENERAL DESCRIPTION

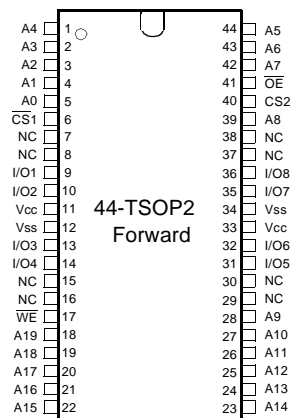
The K6X8008T2B families are fabricated by SAMSUNG's advanced full CMOS process technology. The families support various operating temperature range for user flexibility of system design. The families also support low data retention voltage for battery back-up operation with low data retention current.

### PRODUCT FAMILY

Product Family	Operating Temperature	Vcc Range	Speed	Power Dissipation		PKG Type
				Standby (Isb1, Max)	Operating (Icc2, Max)	
K6X8008T2B-F	Industrial(-40~85°C)	2.7~3.6V	55 <sup>1)</sup> /70ns	30μA	40mA	44-TSOP2-400F
K6X8008T2B-Q	Automotive(-40~125°C)		70ns	40μA		

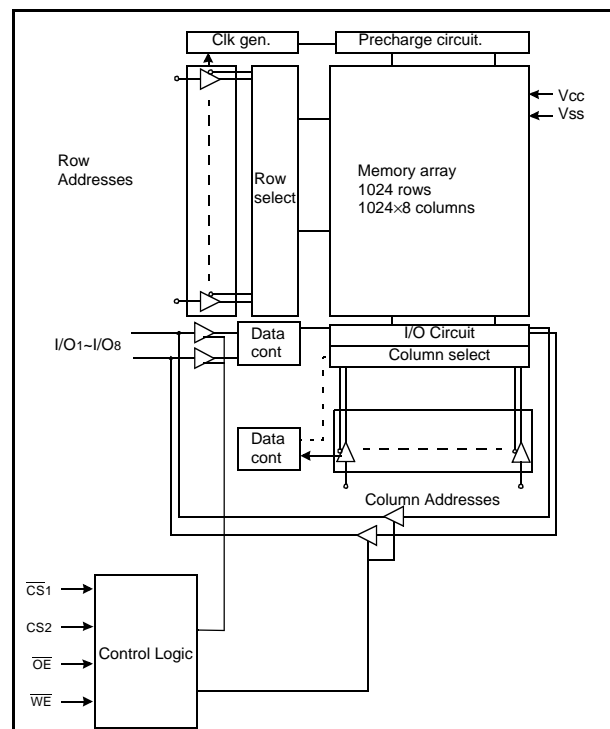
1. This parameter is measured with 50pF test load (Vcc=3.0~3.6V).

### PIN DESCRIPTION



Name	Function	Name	Function
$\overline{CS1}$ , $\overline{CS2}$	Chip Select Inputs	Vcc	Power
$\overline{OE}$	Output Enable Input	Vss	Ground
$\overline{WE}$	Write Enable Input	A0~A19	Address Inputs
I/O1~I/O8	Data Inputs/Outputs	NC	No Connect

### FUNCTIONAL BLOCK DIAGRAM



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## PRODUCT LIST

Industrial Temperature Products(-40~85°C)		Automotive Temperature Products(-40~125°C)	
Part Name	Function	Part Name	Function
K6X8008T2B-TF55 <sup>1)</sup> K6X8008T2B-TF70	44-TSOP2-F, 55ns, LL 44-TSOP2-F, 70ns, LL	K6X8008T2B-TQ70	44-TSOP2-F, 70ns, L

1. Operating voltage range is 3.0~3.6V

## FUNCTIONAL DESCRIPTION

CS <sub>1</sub>	CS <sub>2</sub>	OE	WE	I/O <sub>1-8</sub>	Mode	Power
H	X	X	X	High-Z	Deselected	Standby
X	L	X	X	High-Z	Deselected	Standby
L	H	H	H	High-Z	Output Disabled	Active
L	H	L	H	Dout	Read	Active
L	H	X	L	Din	Write	Active

Note: X means don't care. (Must be low or high state)

## ABSOLUTE MAXIMUM RATINGS<sup>1)</sup>

Item	Symbol	Ratings	Unit	Remark
Voltage on any pin relative to Vss	V <sub>IN</sub> , V <sub>OUT</sub>	-0.2 to V <sub>CC</sub> +0.3 (max. 3.9V)	V	-
Voltage on Vcc supply relative to Vss	V <sub>CC</sub>	-0.2 to 3.9	V	-
Power Dissipation	P <sub>D</sub>	1.0	W	-
Storage temperature	T <sub>STG</sub>	-65 to 150	°C	-
Operating Temperature	T <sub>A</sub>	-40 to 85	°C	K6X8008T2B-F
		-40 to 125	°C	K6X8008T2B-Q

1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation should be restricted to recommended operating condition. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## RECOMMENDED DC OPERATING CONDITIONS<sup>1)</sup>

Item	Symbol	Product	Min	Typ	Max	Unit
Supply voltage	V <sub>CC</sub>	K6X8008T2B Family	2.7	3.0/3.3	3.6	V
Ground	V <sub>SS</sub>	All Family	0	0	0	V
Input high voltage	V <sub>IH</sub>	K6X8008T2B Family	2.2	-	V <sub>CC</sub> +0.3 <sup>2)</sup>	V
Input low voltage	V <sub>IL</sub>	K6X8008T2B Family	-0.3 <sup>3)</sup>	-	0.6	V

Note:

1. Industrial Product: T<sub>A</sub>=-40 to 85°C, otherwise specified.  
Automotive Product: T<sub>A</sub>=-40 to 125°C, otherwise specified.
2. Overshoot: V<sub>CC</sub>+3.0V in case of pulse width ≤30ns.
3. Undershoot: -3.0V in case of pulse width ≤30ns.
4. Overshoot and undershoot are sampled, not 100% tested.

## CAPACITANCE<sup>1)</sup> (f=1MHz, T<sub>A</sub>=25°C)

Item	Symbol	Test Condition	Min	Max	Unit
Input capacitance	C <sub>IN</sub>	V <sub>IN</sub> =0V	-	8	pF
Input/Output capacitance	C <sub>IO</sub>	V <sub>IO</sub> =0V	-	10	pF

1. Capacitance is sampled, not 100% tested.

## DC AND OPERATING CHARACTERISTICS

Item	Symbol	Test Conditions	Min	Typ	Max	Unit	
Input leakage current	I <sub>LI</sub>	V <sub>IN</sub> =V <sub>SS</sub> to V <sub>CC</sub>	-1	-	1	μA	
Output leakage current	I <sub>LO</sub>	$\overline{CS}_1$ =V <sub>IH</sub> , CS <sub>2</sub> =V <sub>IL</sub> or $\overline{OE}$ =V <sub>IH</sub> or $\overline{WE}$ =V <sub>IL</sub> , V <sub>IO</sub> =V <sub>SS</sub> to V <sub>CC</sub>	-1	-	1	μA	
Average operating current	I <sub>CC1</sub>	Cycle time=1μs, 100%duty, I <sub>IO</sub> =0mA, $\overline{CS}_1$ ≤0.2V, CS <sub>2</sub> ≥V <sub>CC</sub> -0.2V, V <sub>IN</sub> ≤0.2V or V <sub>IN</sub> ≥V <sub>CC</sub> -0.2V	-	-	3	mA	
	I <sub>CC2</sub>	Cycle time=Min, I <sub>IO</sub> =0mA, 100% duty, $\overline{CS}_1$ =V <sub>IL</sub> , CS <sub>2</sub> =V <sub>IH</sub> , V <sub>IN</sub> =V <sub>IL</sub> or V <sub>IH</sub>	-	-	40	mA	
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 2.1mA	-	-	0.4	V	
Output high voltage	V <sub>OH</sub>	I <sub>OH</sub> = -1.0mA	2.4	-	-	V	
Standby Current(TTL)	I <sub>SB</sub>	$\overline{CS}_1$ =V <sub>IH</sub> , CS <sub>2</sub> =V <sub>IL</sub> , Other inputs=V <sub>IH</sub> or V <sub>IL</sub>	-	-	0.4	mA	
Standby Current(CMOS)	I <sub>SB1</sub>	Other input =0~V <sub>CC</sub> , 1) $\overline{CS}_1$ ≥V <sub>CC</sub> -0.2V, CS <sub>2</sub> ≥V <sub>CC</sub> -0.2V ( $\overline{CS}_1$ controlled) or 2) 0V≤CS <sub>2</sub> ≤0.2V(CS <sub>2</sub> controlled)	K6X8008T2B-F	-	-	30	μA
		K6X8008T2B-Q	-	-	40		

## AC OPERATING CONDITIONS

### TEST CONDITIONS (Test Load and Input/Output Reference)

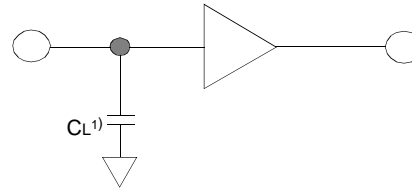
Input pulse level: 0.4 to 2.2V

Input rising and falling time: 5ns

Input and output reference voltage: 1.5V

Output load(see right):  $C_L=100\text{pF}+1\text{TTL}$

$C_L=50\text{pF}+1\text{TTL}$



1. Including scope and jig capacitance

## AC CHARACTERISTICS ( $V_{CC}=2.7\sim 3.6\text{V}$ , Industrial product: $T_A=-40$ to $85^\circ\text{C}$ , Automotive product: $T_A=-40$ to $125^\circ\text{C}$ )

Parameter List		Symbol	Speed Bins				Units
			55ns <sup>1)</sup>		70ns		
			Min	Max	Min	Max	
Read	Read Cycle Time	tRC	55	-	70	-	ns
	Address Access Time	tAA	-	55	-	70	ns
	Chip Select to Output	tCO	-	55	-	70	ns
	Output Enable to Valid Output	tOE	-	25	-	35	ns
	Chip Select to Low-Z Output	tLZ	10	-	10	-	ns
	Output Enable to Low-Z Output	tOLZ	5	-	5	-	ns
	Chip Disable to High-Z Output	tHZ	0	20	0	25	ns
	Output Disable to High-Z Output	tOHZ	0	20	0	25	ns
	Output Hold from Address Change	tOH	10	-	10	-	ns
Write	Write Cycle Time	tWC	55	-	70	-	ns
	Chip Select to End of Write	tCW	45	-	60	-	ns
	Address Set-up Time	tAS	0	-	0	-	ns
	Address Valid to End of Write	tAW	45	-	60	-	ns
	Write Pulse Width	tWP	40	-	50	-	ns
	Write Recovery Time	tWR	0	-	0	-	ns
	Write to Output High-Z	tWHZ	0	20	0	20	ns
	Data to Write Time Overlap	tDW	25	-	30	-	ns
	Data Hold from Write Time	tDH	0	-	0	-	ns
	End Write to Output Low-Z	tOW	5	-	5	-	ns

1. Voltage range is 3.0V~3.6V for industrial product.

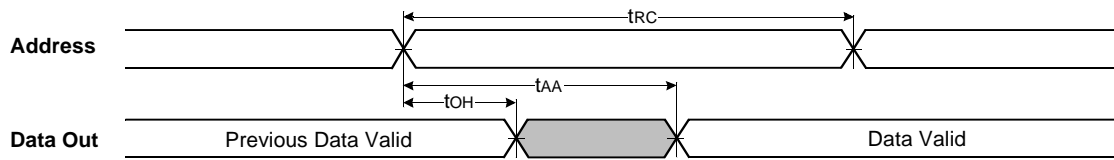
## DATA RETENTION CHARACTERISTICS

Item	Symbol	Test Condition	Min	Typ	Max	Unit
V <sub>CC</sub> for data retention	V <sub>DR</sub>	$\overline{CS}_1 \geq V_{CC}-0.2V^{1)}$	1.5	-	3.6	V
Data retention current	I <sub>DR</sub>	$V_{CC}=1.5V, \overline{CS}_1 \geq V_{CC}-0.2V^{1)}$	-	-	6	$\mu\text{A}$
		K6X8008T2B-Q			10	
Data retention set-up time	t <sub>SDR</sub>	See data retention waveform	0	-	-	ms
Recovery time	t <sub>RDR</sub>		5	-	-	

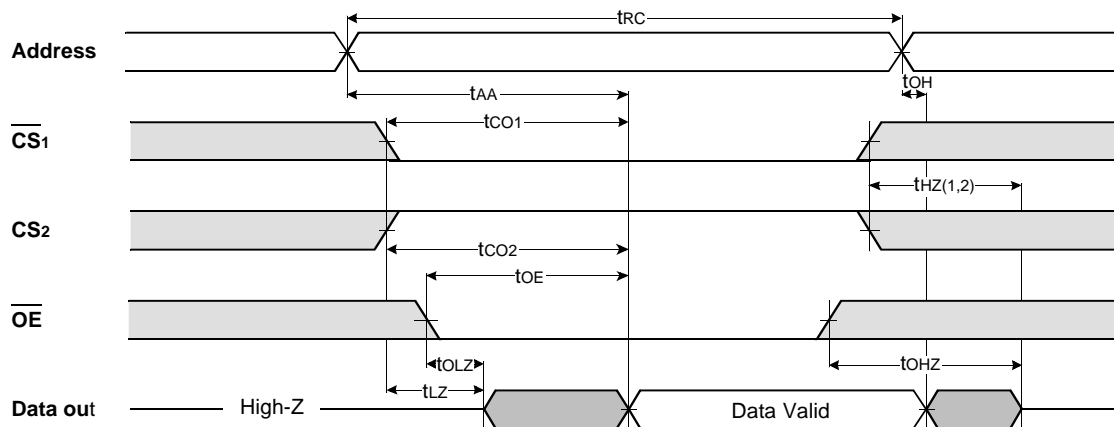
1.  $\overline{CS}_1 \geq V_{CC}-0.2V, CS_2 \geq V_{CC}-0.2V$  ( $\overline{CS}_1$  controlled) or  $CS_2 \geq V_{CC}-0.2V$  ( $CS_2$  controlled).

## TIMING DIAGRAMS

**TIMING WAVEFORM OF READ CYCLE(1)** (Address Controlled,  $\overline{CS}_1 = \overline{OE} = V_{IL}$ ,  $CS_2 = \overline{WE} = V_{IH}$ )



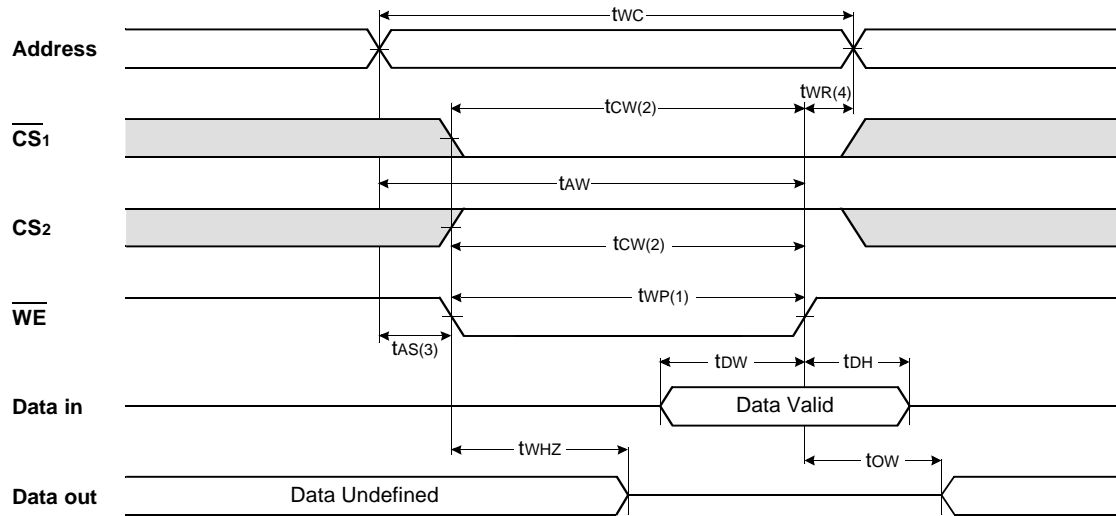
**TIMING WAVEFORM OF READ CYCLE(2)** ( $\overline{WE} = V_{IH}$ )



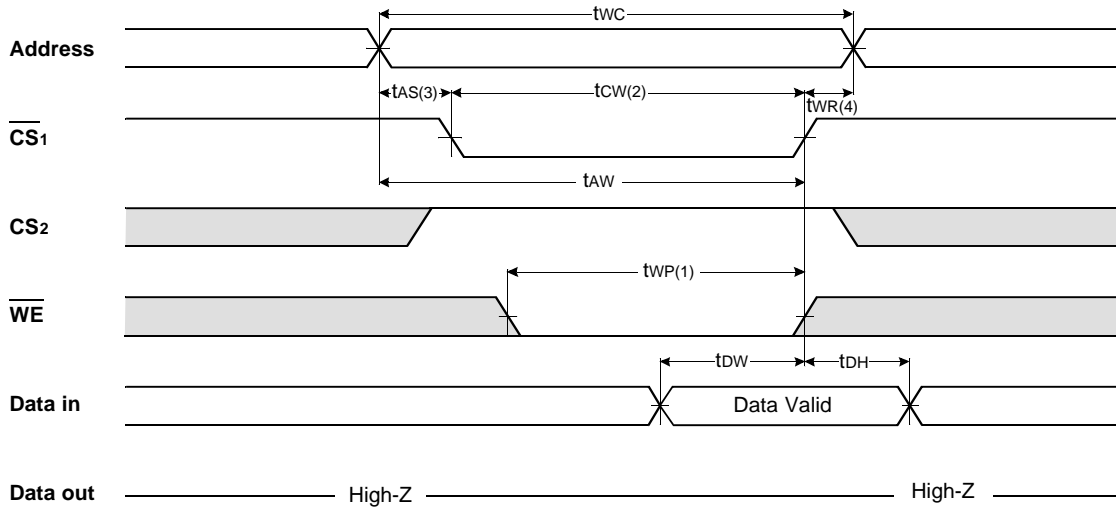
### NOTES (READ CYCLE)

1.  $t_{HZ}$  and  $t_{OHZ}$  are defined as the time at which the outputs achieve the open circuit conditions and are not referenced to output voltage levels.
2. At any given temperature and voltage condition,  $t_{HZ}(\text{Max.})$  is less than  $t_{LZ}(\text{Min.})$  both for a given device and from device to device interconnection.

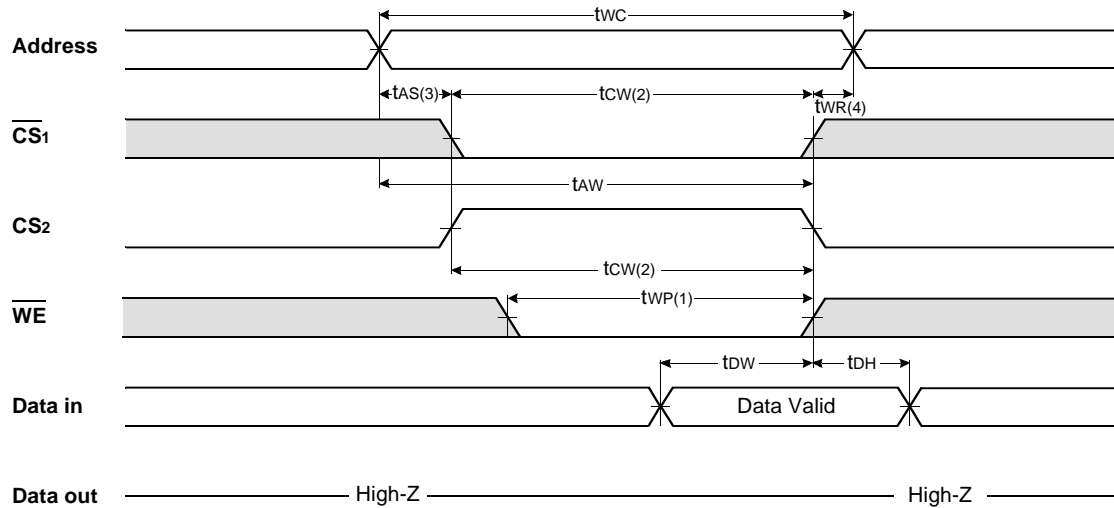
**TIMING WAVEFORM OF WRITE CYCLE(1) ( $\overline{WE}$  Controlled)**



**TIMING WAVEFORM OF WRITE CYCLE(2) ( $\overline{CS_1}$  Controlled)**



## TIMING WAVEFORM OF WRITE CYCLE(3) (CS<sub>2</sub> Controlled)

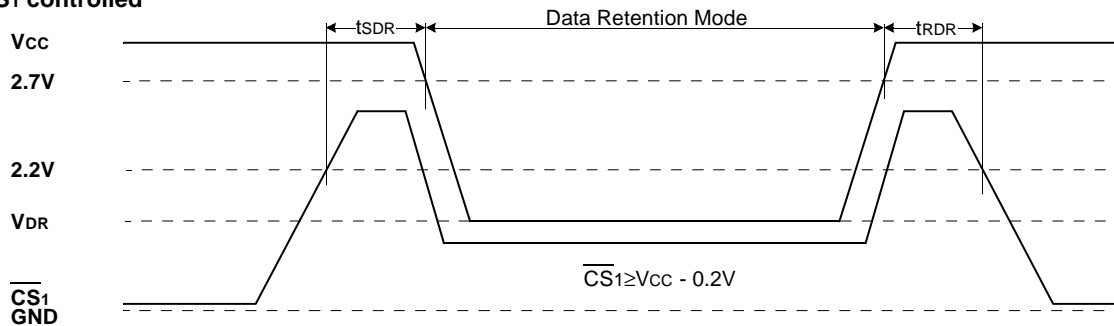


### NOTES (WRITE CYCLE)

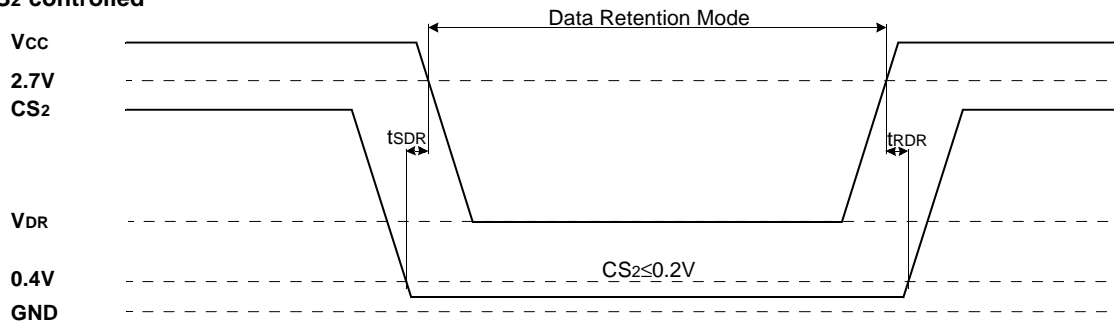
1. A write occurs during the overlap of a low  $\overline{CS_1}$ , a high CS<sub>2</sub> and a low  $\overline{WE}$ . A write begins at the latest transition among  $\overline{CS_1}$  goes low, CS<sub>2</sub> going high and WE going low : A write ends at the earliest transition among CS<sub>1</sub> going high, CS<sub>2</sub> going low and WE going high, tWP is measured from the beginning of write to the end of write.
2. tCW is measured from the CS<sub>1</sub> going low or CS<sub>2</sub> going high to the end of write.
3. tAS is measured from the address valid to the beginning of write.
4. tWR is measured from the end of write to the address change. tWR applied in case a write ends as  $\overline{CS_1}$  or  $\overline{WE}$  going high tWR2 applied in case a write ends as CS<sub>2</sub> going to low.

## DATA RETENTION WAVE FORM

### CS<sub>1</sub> controlled



### CS<sub>2</sub> controlled





## Unit: millimeters(inches)

THIN SMALL OUTLINE PACKAGE TYPE II (400F)

Top View Dimensions:

- Pin 1 indicator circle
- Pin numbers: #1, #22, #23, #44
- Overall width:  $\frac{11.76 \pm 0.20}{0.463 \pm 0.008}$

Side View Dimensions:

- Package height:  $\frac{10.16}{0.400}$
- Lead height:  $\frac{0.45 \sim 0.75}{0.018 \sim 0.030}$
- Lead thickness:  $\frac{0.50}{0.020}$
- Lead angle:  $0 \sim 8^\circ$

Detail View Dimensions:

- Lead thickness:  $\frac{1.00 \pm 0.10}{0.039 \pm 0.004}$
- Lead width:  $\frac{1.20}{0.047}$  MAX.
- Lead angle:  $\frac{0.15}{0.006} \frac{+0.10}{+0.004} \frac{-0.05}{-0.002}$
- Foot length:  $\frac{0.80}{0.0315}$
- Foot thickness:  $\frac{0.35 \pm 0.10}{0.014 \pm 0.004}$
- Foot width:  $\frac{0.805}{0.032}$
- Foot angle:  $\frac{0.10}{0.004}$  MAX
- Foot thickness:  $\frac{0.05}{0.002}$  MIN